NSN 5962-01-291-1903

Memory Microcircuit - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5962-01-291-1903

Body Length:

Between 1.235 inches and 1.285 inches

Body Width:

Between 0.515 inches and 0.600 inches

Body Height:

Between 0.145 inches and 0.187 inches

Maximum Power Dissipation Rating:

800.0 milliwatts

Operating Tempurature Range:

+0.0/+70.0 degrees celsius

Storage Tempurature Range:

-65.0/+125.0 degrees celsius

End Application:

6625-01-081-3402

Features Provided:

3-state output and ultraviolet erasable and low power

Inclosure Material:

Ceramic

Inclosure Configuration:

Dual-in-line

Output Logic Form:

N-type metal oxide-semiconductor logic

Input Circuit Pattern:

11 input

Terminal Surface Treatment:

Solder

Voltage Rating And Type Per Characteristic:

20.0 volts power source

Time Rating Per Chacteristic:

450.00 nanoseconds propagation delay time, low to high level output and 450.00 nanoseconds propagation delay time, high to low level output

output

Memory Device Type:

Rom

Terminal Type And Quantity:

24 printed circuit

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

Yes - demil/mli

Fiig:

A458a0